ON Semiconductor

Is Now

Onsemi

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Complementary Darlington Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Electrically Similar to Popular TIP31 and TIP32 Series
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*



ON Semiconductor®

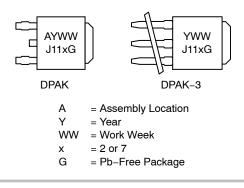
http://onsemi.com

SILICON POWER TRANSISTORS 2 AMPERES 100 VOLTS, 20 WATTS



DPAK CASE 369C DPAK-3 CASE 369D

MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	100	Vdc
Collector-Base Voltage	V _{CB}	100	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current Continuous Peak	lc	2 4	Adc
Base Current	Ι _Β	50	mAdc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	20 0.16	W W/°C
Total Power Dissipation (Note1) @ T _A = 25°C Derate above 25°C	PD	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ hetaJA}$	71.4	°C/W

1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			1	1
Collector-Emitter Sustaining Voltage (Note 2) $(I_{C} = 30 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	100	-	Vdc
Collector Cutoff Current ($V_{CE} = 50 \text{ Vdc}, I_B = 0$)	I _{CEO}	-	20	μAdc
Collector Cutoff Current ($V_{CB} = 100 \text{ Vdc}, I_E = 0$)	Ісво	_	20	μAdc
Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	2	mAdc
Collector–Cutoff Current ($V_{CB} = 80 Vdc$, $I_E = 0$)	Ісво	_	10	μAdc
Emitter–Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	2	mAdc
ON CHARACTERISTICS				
DC Current Gain ($I_C = 0.5 \text{ Adc}, V_{CE} = 3 \text{ Vdc}$) ($I_C = 2 \text{ Adc}, V_{CE} = 3 \text{ Vdc}$) ($I_C = 4 \text{ Adc}, V_{CE} = 3 \text{ Vdc}$)	h _{FE}	500 1000 200	_ 12,000 _	_
Collector-Emitter Saturation Voltage ($I_C = 2 \text{ Adc}, I_B = 8 \text{ mAdc}$) ($I_C = 4 \text{ Adc}, I_B = 40 \text{ mAdc}$)	V _{CE(sat)}	-	2 3	Vdc
Base-Emitter Saturation Voltage (I _C = 4 Adc, I _B = 40 mAdc)	V _{BE(sat)}	_	4	Vdc
Base–Emitter On Voltage (I _C = 2 Adc, V _{CE} = 3 Vdc)	V _{BE(on)}	-	2.8	Vdc
DYNAMIC CHARACTERISTICS			•	
Current–Gain – Bandwidth Product $(I_C = 0.75 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1 \text{ MHz})$	f _T	25	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 Mhz) MJD117, NJVMJD117T4G MJD112, NJVMJD112G, NJVMJD112T4G	C _{ob}	-	200 100	pF

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. *These ratings are applicable when surface mounted on the minimum pad sizes recommended.

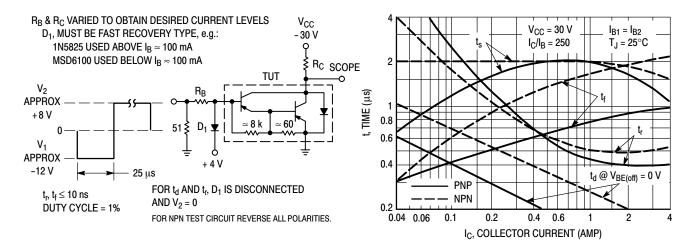




Figure 2. Switching Times

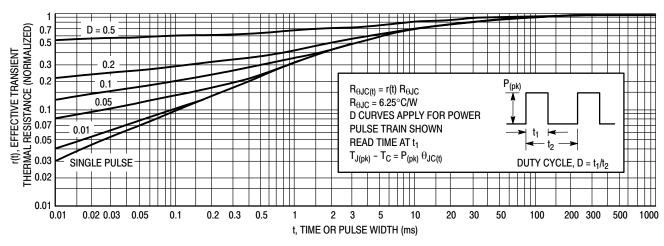


Figure 3. Thermal Response

ACTIVE-REGION SAFE-OPERATING AREA

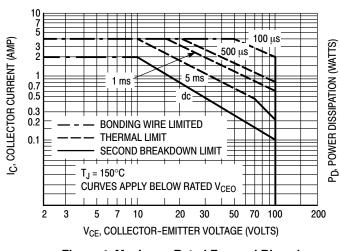


Figure 4. Maximum Rated Forward Biased Safe Operating Area

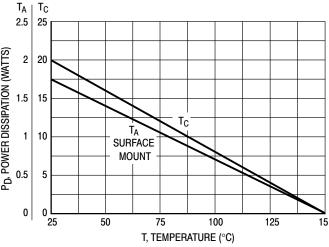
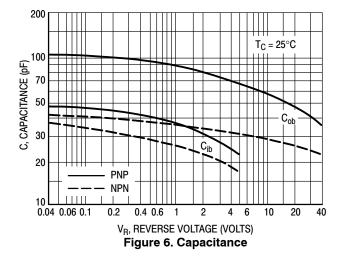


Figure 5. Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{\rm C}$ – $V_{\rm CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

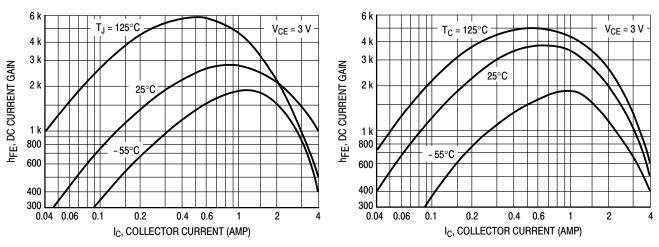
The data of Figures 5 and 6 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



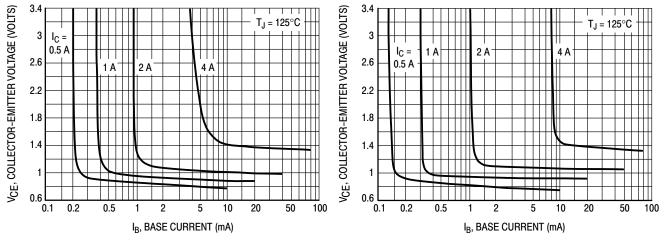
TYPICAL ELECTRICAL CHARACTERISTICS

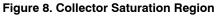
NPN MJD112

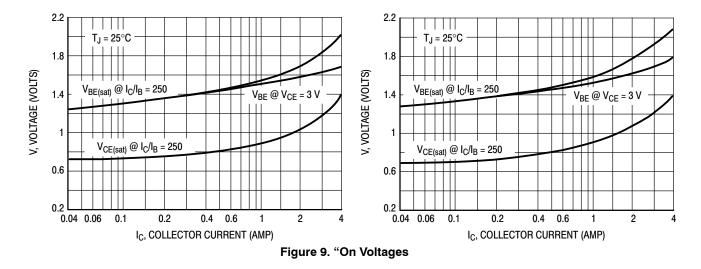
PNP MJD117





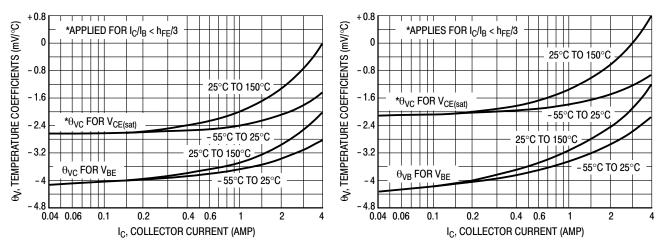




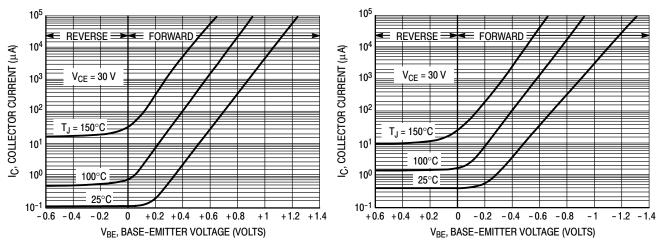


NPN MJD112

PNP MJD117









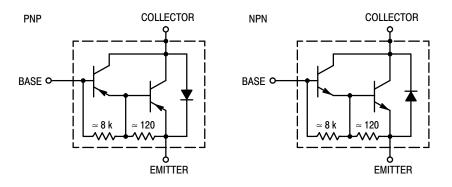


Figure 12. Darlington Schematic

ORDERING INFORMATION

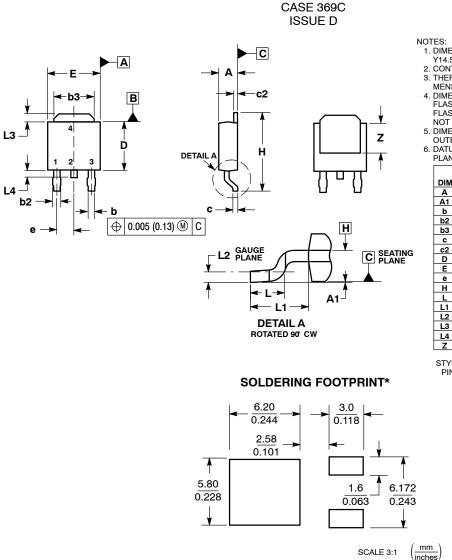
Device	Package Type	Package	Shipping [†]	
MJD112G	DPAK (Pb-Free)	369C	75 Units / Rail	
NJVMJD112G*	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD112-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail	
MJD112RLG	DPAK (Pb-Free)	369C	1,800 Tape & Reel	
MJD112T4G	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
NJVMJD112T4G*	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
MJD117G	DPAK (Pb-Free)	369C	75 Units / Rail	
MJD117-1G	DPAK-3 (Pb-Free)	369D	75 Units / Rail	
MJD117RLG	DPAK (Pb-Free)	369C	1,800 Tape & Reel	
MJD117T4G	DPAK (Pb-Free)	369C	2,500 Tape & Reel	
NJVMJD117T4G*	DPAK (Pb-Free)	369C	2,500 Tape & Reel	

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP

Capable.

PACKAGE DIMENSIONS

DPAK



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

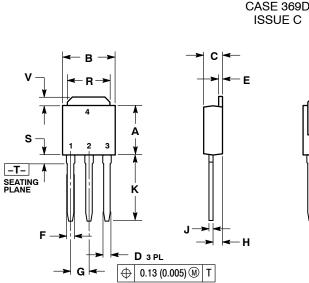
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-WEINFORD 52 and 7.
- THERIMAL FAD CONTOR OF HOME WITHIN DEMENSIONS b3, L3 and Z.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
 DATUMS A AND B ARE DETERMINED AT DATUM DIANUS A
- PLANE H.

	INCHES		MILLIM	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
E	0.250	0.265	6.35	6.73	
е	0.090	BSC	2.29 BSC		
н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74 REF		
L2	0.020	BSC	0.51	BSC	
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0.155		3.93		

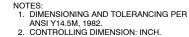
STYLE 1:

PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

PACKAGE DIMENSIONS



IPAK CASE 369D



	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN MAX	
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
Κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155		3.93	

STYLE 1: PIN 1. BASE

z

2. COLLECTOR

3. EMITTER

COLLECTOR 4.

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